

PIN2



NPN Silicon Power Transistors

Features

- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- Complement to 2N6042
- High switching speed

Mechanical Data

- Package: TO-220AB
- Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- Unit Weight: 1.9g
- PIN1 PIN2 PIN3 C PIN2 B PIN1 B PIN1 B B PIN1:Base E PIN1:Base PIN2:Collector PIN3 PIN3:Emitter

■ Maximum Ratings (Ta=25°C unless otherwise noted)

| Item | Symbol | Unit | Value |
|---|-------------------|------|-------------|
| Device marking code | | | 2N6045 |
| Collector-base voltage | V _{CBO} | V | 100 |
| Collector-emitter voltage | V _{CEO} | V | 100 |
| Emitter-base voltage | V_{EBO} | V | 5 |
| Collector current | Ι _C | А | 8 |
| Power dissipation | P _D | W | 5 |
| Thermal resistance, junction-to-ambient (Note1) | R _{thJA} | °C/W | 25 |
| Junction temperature | Tj | °C | -55 to +150 |
| Storage temperature | T _{STG} | °C | -55 to +150 |

Note1: Device mounted on PCB with minimum recommended pad layout and additional heat sink (25mm x 23mm x 15mm) attached.

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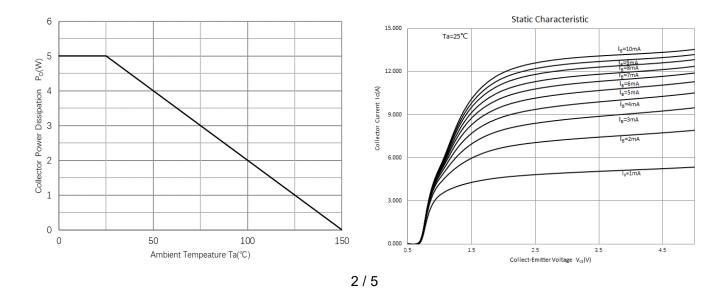




■ Electrical Characteristics (Ta=25 °C unless otherwise noted)

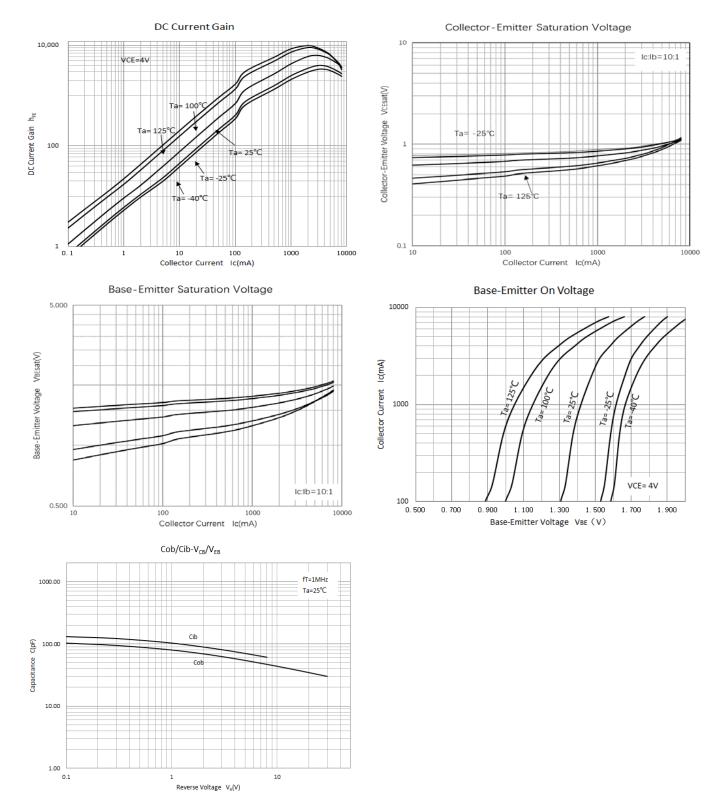
| ltem | Symbol | Unit | Conditions | Min | Тур | Max |
|--------------------------------------|----------------------|------|--|------|-----|-------|
| Collector-base breakdown voltage | V _{(BR)CBO} | V | I _C = 100uA, I _E =0 | 100 | | |
| Collector-emitter breakdown voltage | V _{(BR)CEO} | V | I _C = 1mA, I _B =0 | 100 | | |
| Emitter-base breakdown voltage | $V_{(BR)EBO}$ | V | I _E = 1mA, I _C =0 | 5 | | |
| Collector-base cut-off current | I _{CBO} | μΑ | V _{CB} =100V | | | 20 |
| Collector cutoff current | I _{CEO} | μΑ | V _{CE} =100V | | | 20 |
| Emitter-base cut-off current | I _{EBO} | mA | V _{EB} =5V | | | 2.0 |
| | L | | V _{CE} = 4V, I _C = 3A | 1000 | | 20000 |
| DC current gain | h _{FE} | | V _{CE} = 4V, I _C = 8A | 100 | | |
| Collector-emitter saturation voltage | V _{CE(sat)} | V | I _C = 3A, I _B = 12mA | | | 2.0 |
| Base-emitter saturation voltage | $V_{BE(sat)}$ | V | I _C = 8A, I _B = 80mA | | | 4.5 |
| Base-Emitter Voltage | V _{BE(on)} | V | V_{CE} = 4V, I_{C} = 4A | | | 2.8 |
| Collector-base output capacitance | Cob | pF | V _{CB} =10V,I _E =0A,f=1MHz | | 200 | |

Characteristics(Typical)





Characteristics(Typical)



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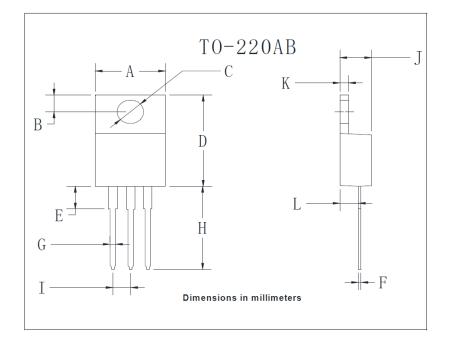




Ordering Information (Example)

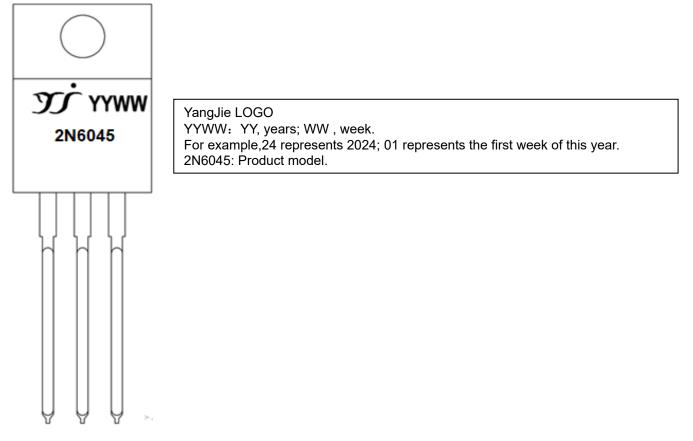
| PREFERED P/N | PACKING CODE | MINIMUM PACKAGE(pcs) | INNER BOX QUANTITY(pcs) | OUTER CARTON QUANTITY(pcs) | DELIVERY MODE |
|--------------|--------------|-------------------------|----------------------------|-------------------------------|---------------|
| 2N6045 | B1 | 50/Tube | 1000 | 2000 | Tube |

■ TO-220AB Package information



| TO-220AB | | | | |
|----------|-------|-------|--|--|
| Dim | Min | Max | | |
| А | 9.95 | 10.35 | | |
| В | 2.55 | 2.95 | | |
| С | 3.8 | 4.0 | | |
| D | 14.95 | 15.25 | | |
| Е | 3.75 | 4.25 | | |
| F | 0.26 | 0.5 | | |
| G | 0.68 | 0.94 | | |
| Н | 13.4 | 13.9 | | |
| I | 2.35 | 2.65 | | |
| J | 4.38 | 4.78 | | |
| K | 1.14 | 1.4 | | |
| L | 2.37 | 2.79 | | |

Marking code







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